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 2018년 2월 5일(월)-7일(수), 강원도 하이원리조트 컨벤션 호텔

## 2018년 2월 6일(화), 14:10-15:55 Room G (봉래II+III, 6층)

## J. Nano-Science & Technology 분과

[TH2-J] Two Dimensional Nano Materials

좌장: 이태우 교수(서울대학교), 정대성 교수(DGIST)

TH2-J-1 14:10-14:40	[초청]
	Light Induced Directed Self-Assembly of Block Copolymers on Chemically
	Modified Graphene
	Sang Ouk Kim, Hyeong Min Jin, and Ju Young kim
	Department of Materials Science & Engineering, KAIST
TH2-J-2 14:40-14:55	Self-Polarized Organic Light Emitting Diodes based on MoS <sub>2</sub> Nanosheets Quyet Van Le <sup>1</sup> , Gyu Jin Choi <sup>2</sup> , Kyoung Soon Choi <sup>3</sup> , Ki Chang Kwon <sup>4</sup> , Ho Won Jang <sup>4</sup> , Jin Seog Gwag <sup>2</sup> , and Soo Young Kim <sup>1</sup> <sup>1</sup> School of Chemical Engineering and Materials Science, Chung-Ang University, <sup>2</sup> Department of Physics, Yeungnam University, <sup>3</sup> Advanced Nano-Surface Research Group, KBSI, <sup>4</sup> Department of Materials Science and Engineering, Research Institute of Advanced Materia
	Layer-Index and Valley-Index of Electrons in 2D Transition Metal
TH2-J-3 14:55-15:10	Dichalcogenides for Optoelectronic Applications: 3R MoS <sub>2</sub> Jaehong Park <sup>1,2</sup> , Cheol Seong Hwang <sup>2</sup> , and Jung-Hae Choi <sup>1</sup> <sup>1</sup> Center for Electronic Materials, KIST, <sup>2</sup> Department of Materials Science and Engineering, and Inter-university Semiconductor Research Center, Seoul National University
	Gas Ambient Effects on Electrical Characteristics of Multi-Layered MoTe2
TH2-J-4	Thin Film Transistors
15:10-15:25	Min Seok Chae, Da Un Kim, Do Bin Kim, Seung Gi Seo, and Sung Hun Jin Department of Electronic Engineering, Incheon National University
TH2-J-5 15:25-15:40	Molecular-Scale Rectifier Employing Hybrid Junction Architecture Consisting of the 2D MoS <sub>2</sub> and the Conjugated Molecule Jaeho Shin, Seunghoon Yang, Chulho Lee, and Gunuk Wang <i>KU-KIST Graduate School of Converging Science and Technology, Korea University</i>
TH2-J-6 15:40-15:55	Accurate First Principles Simulations of a Metal and MoTe <sub>2</sub> Device Using the
	DFT and NEGF
	Maeng-Eun Lee, D. Stradi, J. Wellendorf, P. Khomyakov, U. Vej-Hansen, S.
	Smidstrup, and K. Stokbro Synopsys QuantumWise
	Juli Statuti Andrea Carta and Carta